NEC

DATA SHEET

MOS FIELD EFFECT TRANSISTOR
2SJ648

P-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

DESCRIPTION

The 2SJ648 is a switching device which can be driven directly by a 2.5 V power source.

The 2SJ648 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

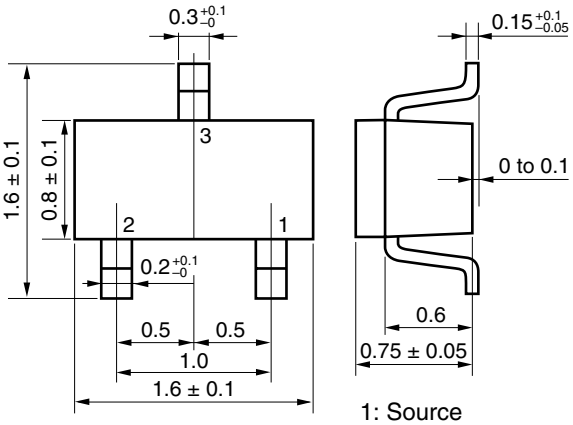
- 2.5 V drive available
- Low on-state resistance
  $R_{DS(on)1}$ = 1.45 Ω MAX. (V_{GS} = –4.5 V, I_D = –0.2 A)
  $R_{DS(on)2}$ = 1.55 Ω MAX. (V_{GS} = –4.0 V, I_D = –0.2 A)
  $R_{DS(on)3}$ = 2.98 Ω MAX. (V_{GS} = –2.5 V, I_D = –0.15 A)

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SJ648	SC-75 (USM)

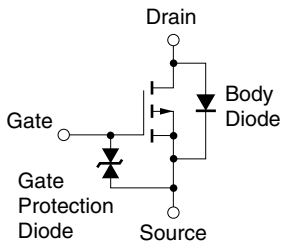
Marking: H1

★ PACKAGE DRAWING (Unit: mm)



1: Source
2: Gate
3: Drain

EQUIVALENT CIRCUIT



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Drain to Source Voltage (V_{GS} = 0 V)	V_{DSS}	–20	V
Gate to Source Voltage (V_{DS} = 0 V)	V_{GSS}	∓12	V
Drain Current (DC)	$I_{D(DC)}$	∓0.4	A
Drain Current (pulse) Note1	$I_{D(pulse)}$	∓1.6	A
Total Power Dissipation Note2	P_T	200	mW
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	–55 to +150	°C

Notes 1. PW ≤ 10 μs, Duty Cycle ≤ 1%

2. Mounted on ceramic substrate of 300 mm^2 x 0.64 mm.

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

Caution This product is electrostatic-sensitive device due to low ESD capability and should be handled with caution for electrostatic discharge.
V_{ESD} = ±100 V TYP. (C = 200 pF, R = 0 Ω, Single pulse)

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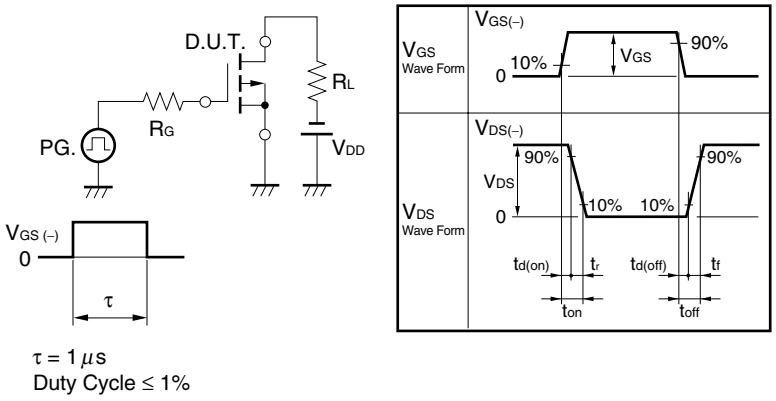
The mark ★ shows major revised points.

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = –20 V, V_{GS} = 0 V			–1.0	μA
Gate Leakage Current	I_{GSS}	V_{GS} = ∓12 V, V_{DS} = 0 V			∓10	μA
Gate Cut-off Voltage	$V_{GS(off)}$	V_{DS} = –10 V, I_D = –1.0 mA	–0.8	–1.3	–1.8	V
Forward Transfer Admittance **Note**	$\|y_{fs}\|$	V_{DS} = –10 V, I_D = –0.2 A	0.2	0.6		S
Drain to Source On-state Resistance **Note**	$R_{DS(on)1}$	V_{GS} = –4.5 V, I_D = –0.2 A		1.17	1.45	Ω
	$R_{DS(on)2}$	V_{GS} = –4.0 V, I_D = –0.2 A		1.25	1.55	Ω
	$R_{DS(on)3}$	V_{GS} = –2.5 V, I_D = –0.15 A		2.25	2.98	Ω
Input Capacitance	C_{iss}	V_{DS} = –10 V		29		pF
Output Capacitance	C_{oss}	V_{GS} = 0 V		15		pF
Reverse Transfer Capacitance	C_{rss}	f = 1 MHz		3.0		pF
Turn-on Delay Time	$t_{d(on)}$	V_{DD} = –10 V, I_D = –0.2 A		23		ns
Rise Time	t_r	V_{GS} = –4.0 V		39		ns
Turn-off Delay Time	$t_{d(off)}$	R_G = 10 Ω		50		ns
Fall Time	t_f			33		ns
Body Diode Forward Voltage	$V_{F(S-D)}$	I_F = 0.4 A, V_{GS} = 0 V		0.93		V

Note Pulsed PW ≤ 350 μs, Duty Cycle ≤ 2%

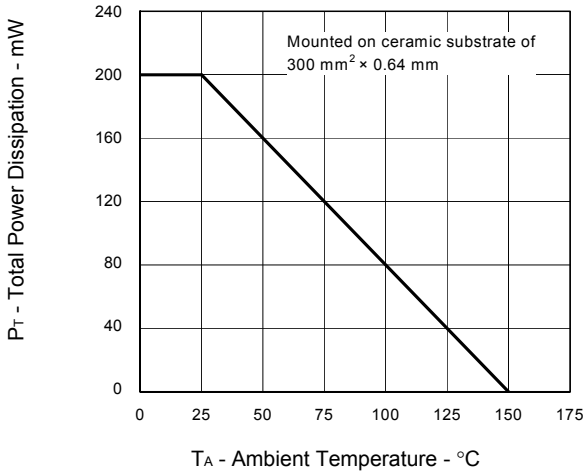
TEST CIRCUIT SWITCHING TIME



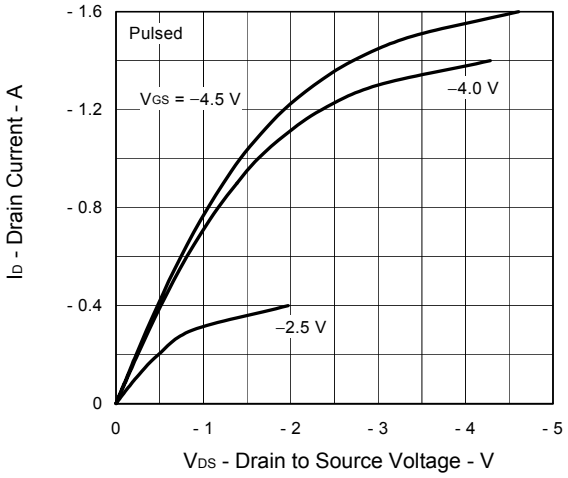
τ = 1 μs
Duty Cycle ≤ 1%

TYPICAL CHARACTERISTICS (T_A = 25°C)

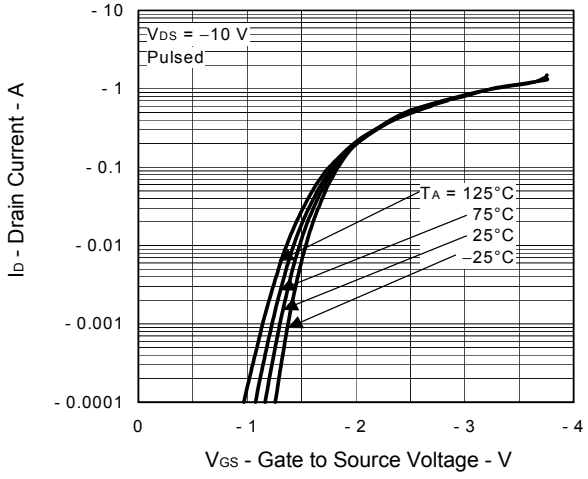
TOTAL POWER DISSIPATION vs.
AMBIENT TEMPERATURE



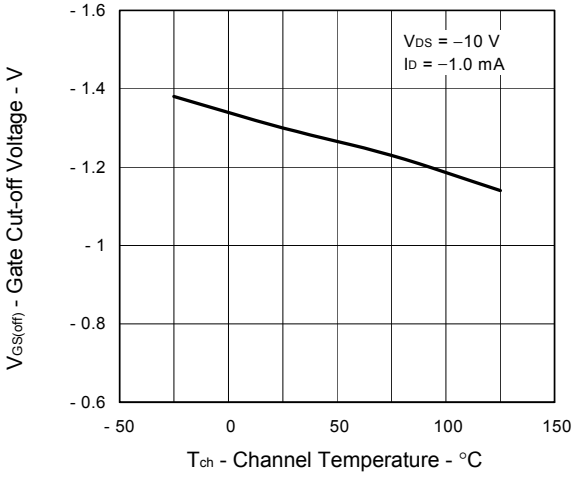
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



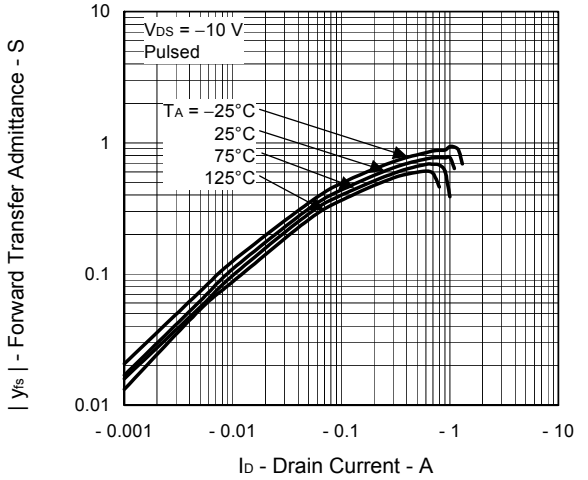
FORWARD TRANSFER CHARACTERISTICS



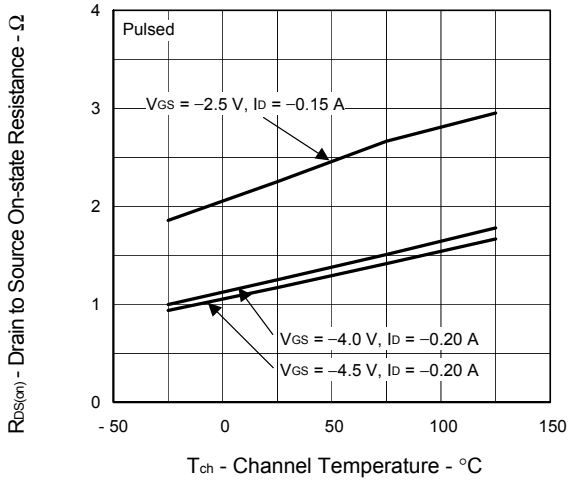
GATE CUT-OFF VOLTAGE vs.
CHANNEL TEMPERATURE



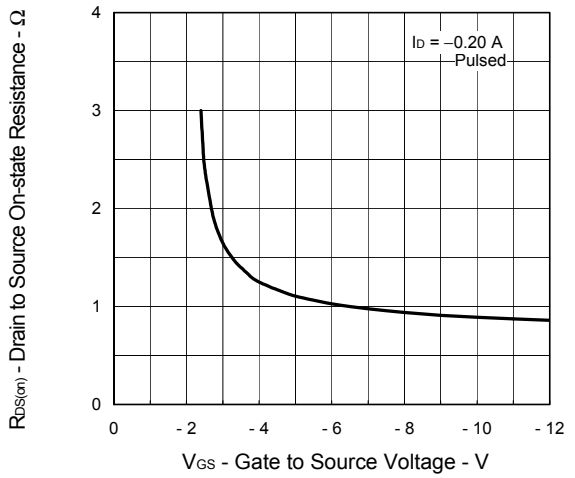
FORWARD TRANSFER ADMITTANCE vs.
DRAIN CURRENT



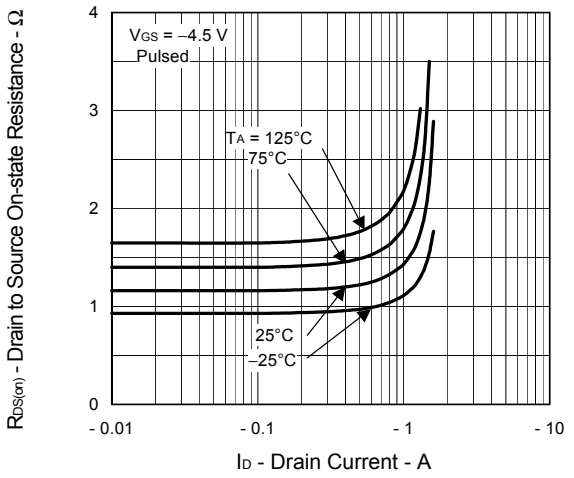
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
CHANNEL TEMPERATURE



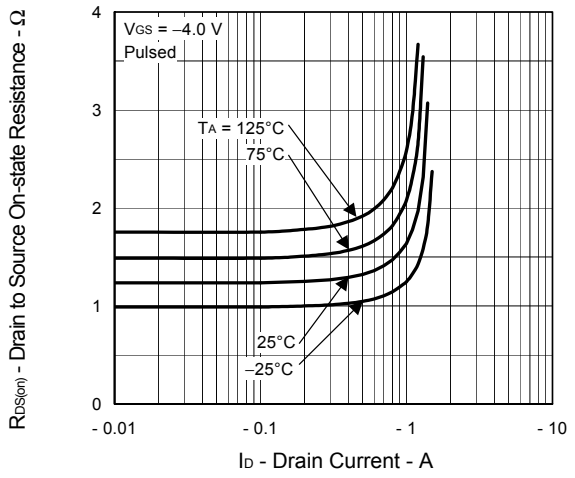
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
GATE TO SOURCE VOLTAGE



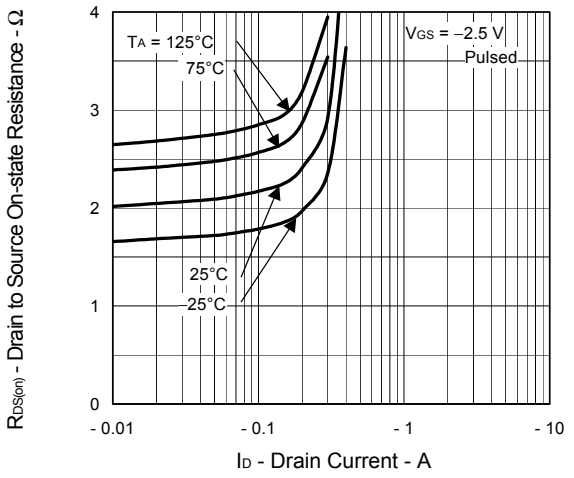
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
DRAIN CURRENT



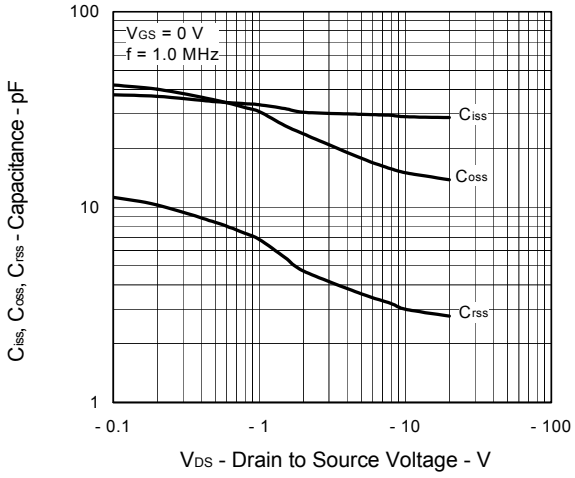
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
DRAIN CURRENT



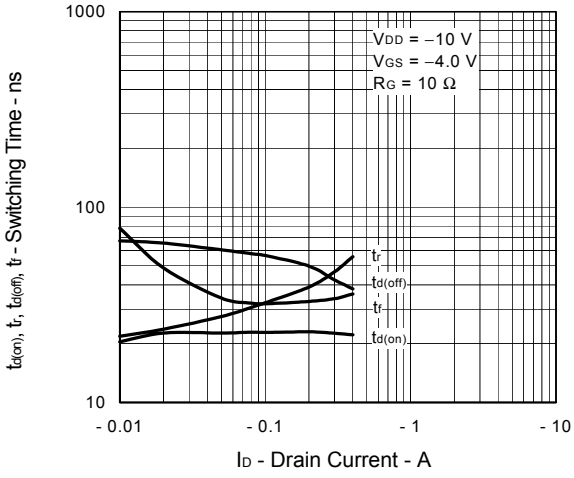
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
DRAIN CURRENT



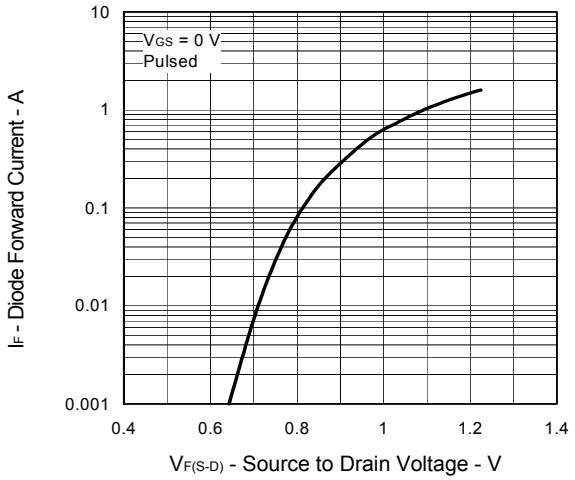
CAPACITANCE vs.
DRAIN TO SOURCE VOLTAGE



SWITCHING CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



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